

APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of InventionLOW TEMPERATURE POLYSILICON THIN FILM TRANSISTOR AND
METHOD OF FABRICATING LIGHTLY DOPED DRAIN THEREOF

Application Type : regular, utility
Attorney Docket Number : 13530-US-PA

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as my attorney(s) or agent(s) to prosecute the application identified above, and to transact all
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